

2SJ656

2SJ656 Information



Part Number	28J656
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Description	MOSFET P-CH 100V 18A TO-220ML
Package	TO-220-3 Full Pack
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

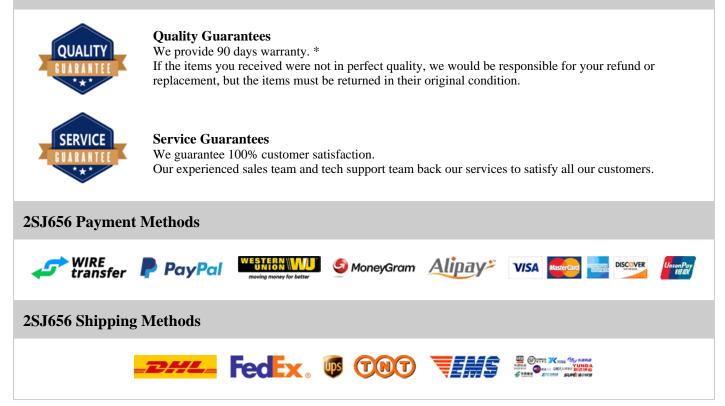
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2SJ656 Specifications

Manufacturer Part Number	2SJ656
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	-
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	18A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4V, 10V
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	74nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4200pF @ 20V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	2W (Ta), 30W (Tc)
Rds On (Max) @ Id, Vgs	75.5 mOhm @ 9A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220ML
Package / Case	TO-220-3 Full Pack
	Report errors?

2SJ656 Guarantees



If you have any question about 2SJ656, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com